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Stocking Distributor

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[Powerex Inc.](#)
[CM300DY-28H](#)

For any questions, you can email us directly:

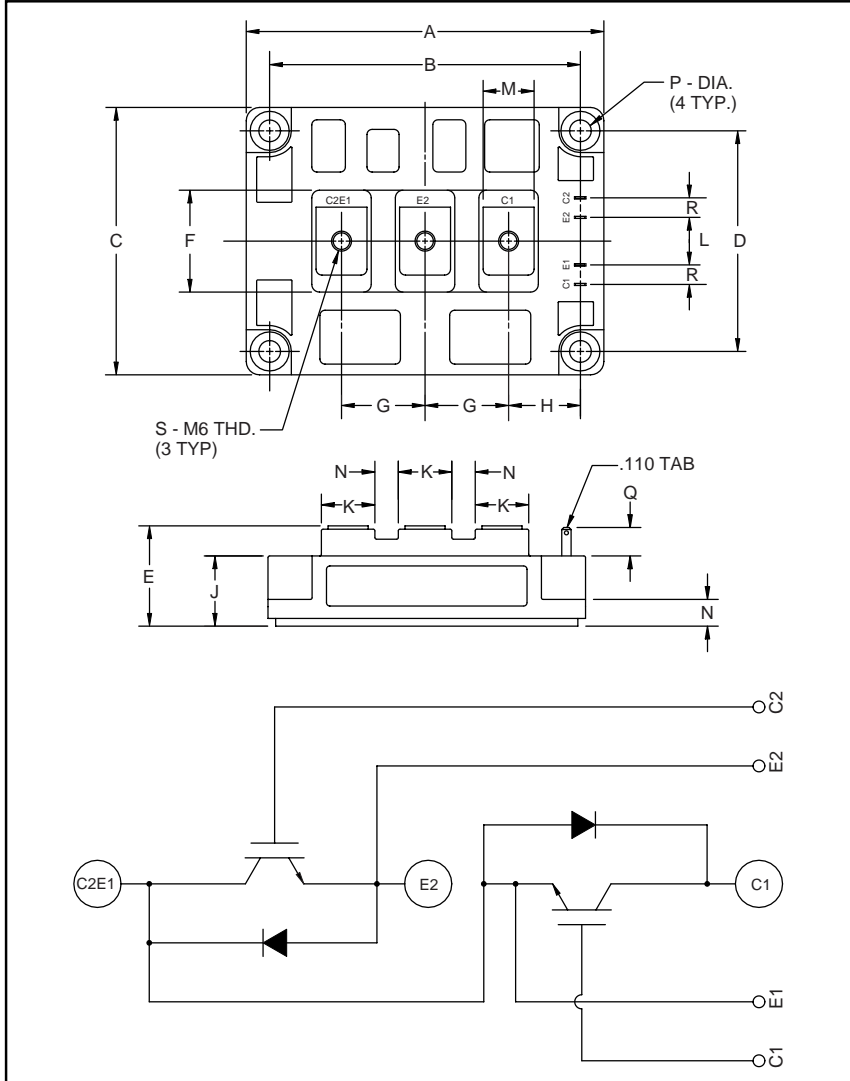
sales@integrated-circuit.com



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM300DY-28H

**Dual IGBTMOD™
H-Series Module
300 Amperes/1400 Volts**



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.33	110.0
B	3.661±0.01	93.0±0.25
C	3.15	80.0
D	2.441±0.01	62.0±0.25
E	1.18 Max.	30.0 Max.
F	1.18	30.0
G	0.98	25.0
H	0.85	21.5
J	0.83	21.2

Dimensions	Inches	Millimeters
K	0.71	18.0
L	0.59	15.0
M	0.55	14.0
N	0.28	7.0
P	0.26 Dia.	Dia. 6.5
Q	0.33	8.5
R	0.24	6.0
S	M6 Metric	M6



Description:

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- Low Drive Power
- Low $V_{CE(sat)}$
- Discrete Super-Fast Recovery (135ns) Free-Wheel Diode
- High Frequency Operation (20-25kHz)
- Isolated Baseplate for Easy Heat Sinking

Applications:

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

Ordering Information:

Example: Select the complete part module number you desire from the table below -i.e. CM300DY-28H is a 1400V (V_{CES}), 300 Ampere Dual IGBTMOD™ Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 50)
CM	300	28



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Absolute Maximum Ratings, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	CM300DY-28H	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	V_{CES}	1400	Volts
Gate-Emitter Voltage	V_{GES}	± 20	Volts
Collector Current	I_C	300	Amperes
Peak Collector Current	I_{CM}	600*	Amperes
Diode Forward Current	I_F	300	Amperes
Diode Forward Surge Current	I_{FM}	600*	Amperes
Power Dissipation	P_d	2100	Watts
Max. Mounting Torque M6 Terminal Screws	-	26	in-lb
Max. Mounting Torque M6 Mounting Screws	-	26	in-lb
Module Weight (Typical)	-	500	Grams
V Isolation	V_{RMS}	2500	Volts

* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

Static Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	I_{CES}	$V_{\text{CE}} = V_{\text{CES}}, V_{\text{GE}} = 0\text{V}$	-	-	1.0	mA
Gate Leakage Current	I_{GES}	$V_{\text{GE}} = V_{\text{GES}}, V_{\text{CE}} = 0\text{V}$	-	-	0.5	μA
Gate-Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$I_C = 30\text{mA}, V_{\text{CE}} = 10\text{V}$	5.0	6.5	8.0	Volts
Collector-Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	$I_C = 300\text{A}, V_{\text{GE}} = 15\text{V}$	-	3.1	4.2**	Volts
		$I_C = 300\text{A}, V_{\text{GE}} = 15\text{V}, T_j = 150\text{ }^\circ\text{C}$	-	2.95	-	Volts
Total Gate Charge	Q_G	$V_{\text{CC}} = 600\text{V}, I_C = 300\text{A}, V_{\text{GE}} = 15\text{V}$	-	1530	-	nC
Diode Forward Voltage	V_{FM}	$I_E = 300\text{A}, V_{\text{GE}} = 0\text{V}$	-	-	3.8	Volts

** Pulse width and repetition rate should be such that device junction temperature rise is negligible.

Dynamic Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units	
Input Capacitance	C_{ies}		-	-	60	nF	
Output Capacitance	C_{oes}	$V_{\text{GE}} = 0\text{V}, V_{\text{CE}} = 10\text{V}, f = 1\text{MHz}$	-	-	21	nF	
Reverse Transfer Capacitance	C_{res}		-	-	12	nF	
Resistive	Turn-on Delay Time	$t_{\text{d(on)}}$	-	-	250	ns	
							Load
Switching	Turn-off Delay Time	$t_{\text{d(off)}}$	-	-	350	ns	
							Times
Diode Reverse Recovery Time	t_{rr}	$I_E = 300\text{A}, di_E/dt = -600\text{A}/\mu\text{s}$	-	-	300	ns	
Diode Reverse Recovery Charge	Q_{rr}	$I_E = 300\text{A}, di_E/dt = -600\text{A}/\mu\text{s}$	-	3.0	-	μC	

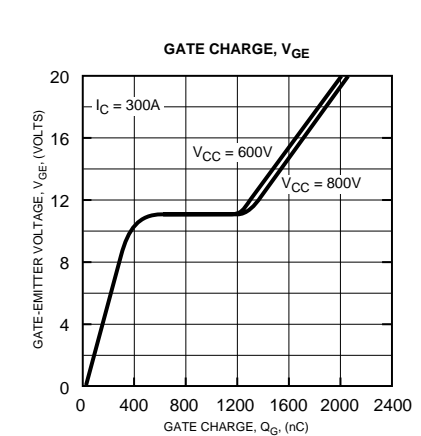
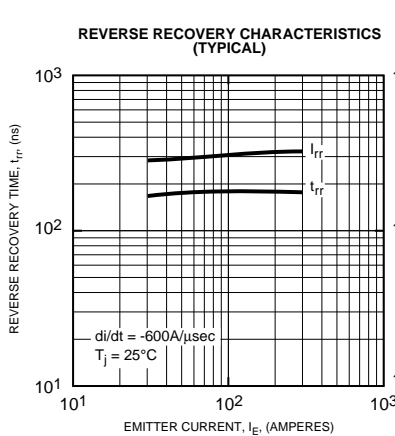
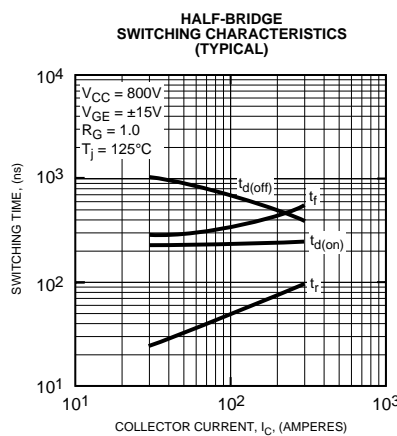
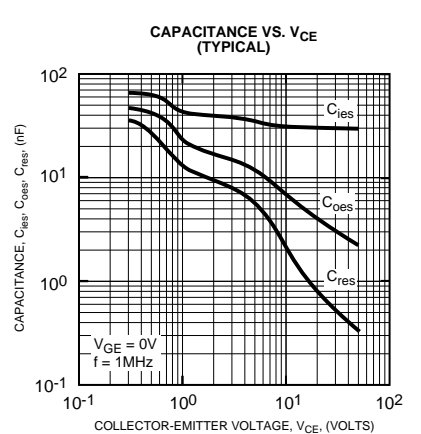
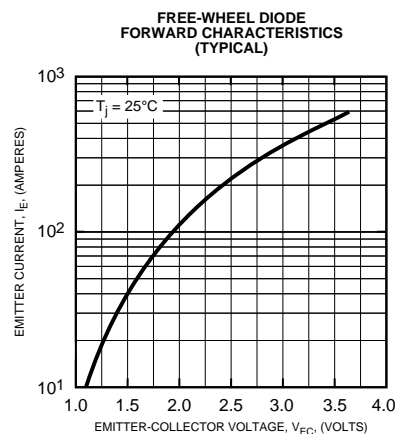
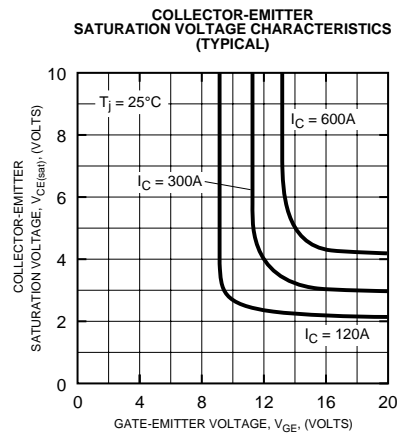
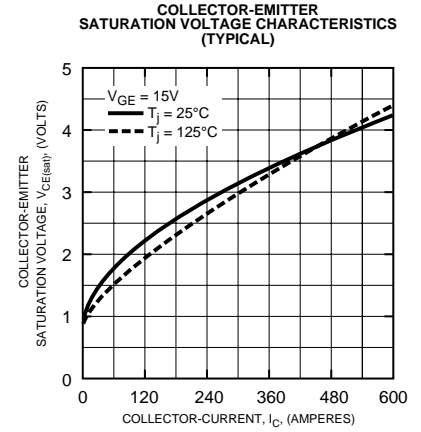
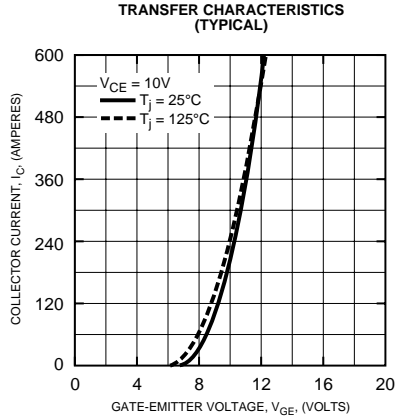
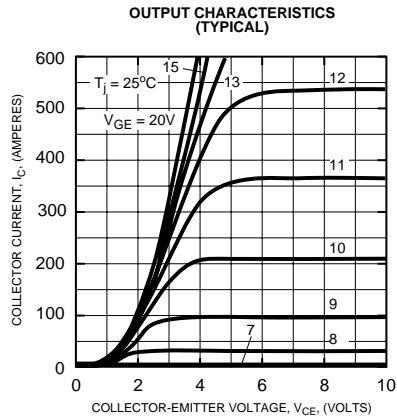
Thermal and Mechanical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)}}$	Per IGBT	-	-	0.06	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)}}$	Per FWDi	-	-	0.12	$^\circ\text{C}/\text{W}$
Contact Thermal Resistance	$R_{\text{th(c-f)}}$	Per Module, Thermal Grease Applied	-	-	0.035	$^\circ\text{C}/\text{W}$



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